NSN 5962-01-326-7712

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-326-7712 **Body Length:** 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** Between 0.150 inches and 0.210 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Electrostatic sensitive and high performance and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Current Rating Per Characteristic:** 185.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Memory Device Type:** Prom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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